

SUPPORTING INFORMATION TO

Substrate Grain-Dependent Chemistry of Carburized Planar Anodic TiO₂ on Polycrystalline Ti

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Additional information on SPEM

The Ti $2p_{3/2}$ chemical maps of TiOC_{650} , TiOC_{750} and TiOC_{850} , (TiC/TiO_2 or $\text{TiO}_x/\text{TiO}_2$) were generated by dividing the integrated map obtained in the energy range 456 - 452.15 eV by the integrated map obtained in the energy range 459.85 - 456 eV. The Ti $2p_{3/2}$ chemical maps of TiOC_{550} (TiO_2/BG) were generated by dividing the integrated map obtained in the energy range 459.85 - 456 eV by the integrated map obtained in the energy range 456 - 452.15 eV. The C 1s chemical maps of all TiOC (C/BG) were generated by dividing the integrated map obtained in the energy range 286.85 - 283 eV by the integrated map obtained in the energy range 283 - 279.15 eV.

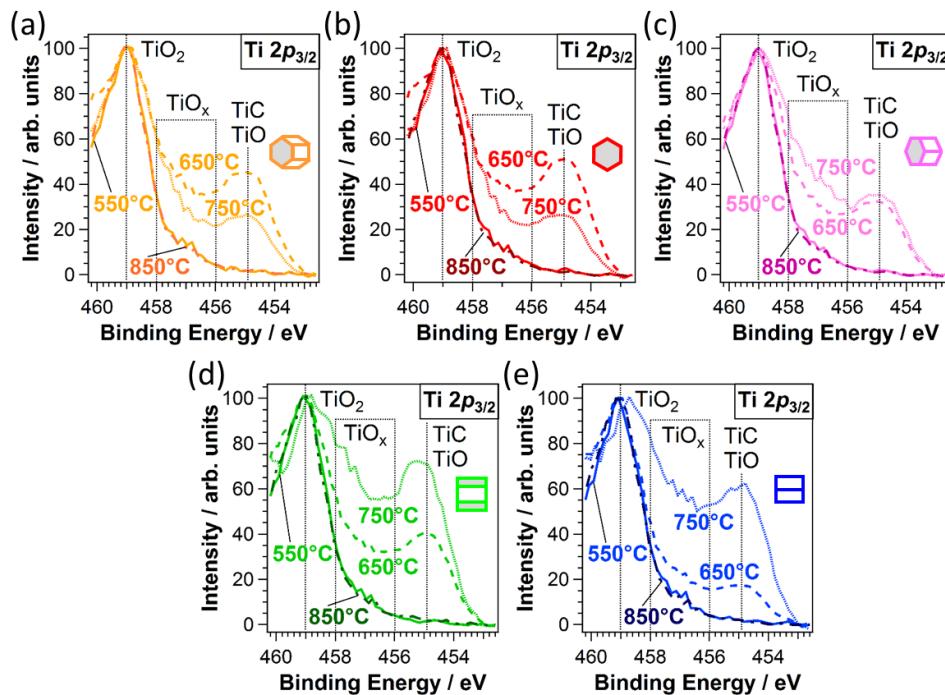


Figure S1. XP spectra from $\text{Ti } 2p_{3/2}$ photoelectron micrographs taken of TiOC on top of five differently oriented substrate grains for the four annealing temperatures. The substrate orientations are (a) $15^\circ \leq \Phi \leq 40^\circ$, $0^\circ \leq \varphi_2 \leq 30^\circ$, (b) $0^\circ \leq \Phi \leq 15^\circ$, $0^\circ \leq \varphi_2 \leq 30^\circ$ (c) $40^\circ \leq \Phi \leq 50^\circ$, $0^\circ \leq \varphi_2 \leq 30^\circ$, (d) $50^\circ \leq \Phi \leq 90^\circ$, $15^\circ \leq \varphi_2 \leq 30^\circ$ (e) $50^\circ \leq \Phi \leq 90^\circ$, $0^\circ \leq \varphi_2 \leq 15^\circ$.

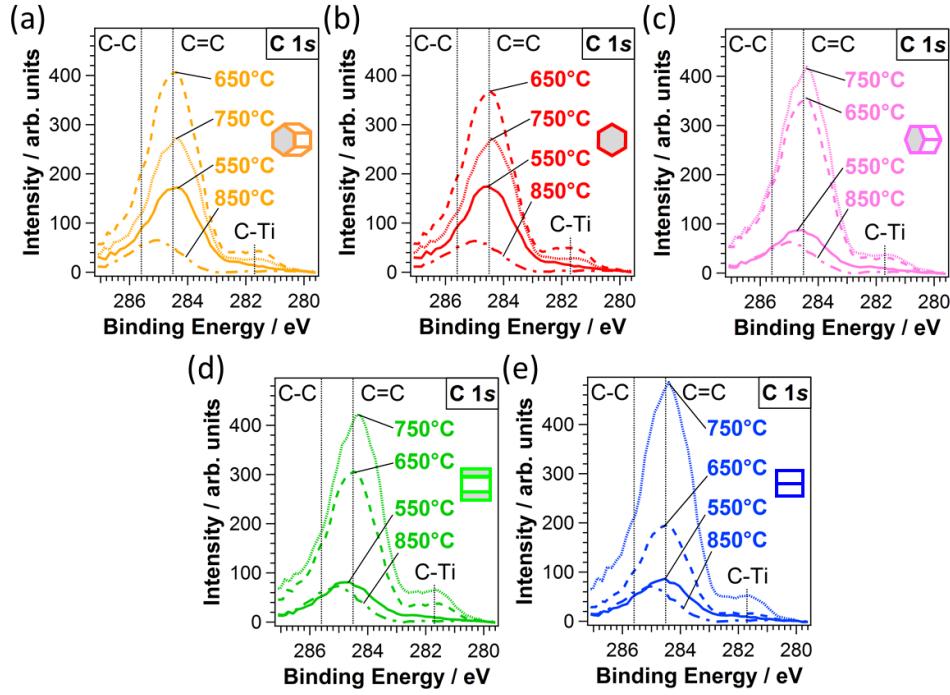


Figure S2. XP spectra from C 1s photoelectron micrographs taken of TiOC on top of five differently oriented substrate grains for the four annealing temperatures. The substrate orientations are (a) $15^\circ \leq \Phi \leq 40^\circ$, $0^\circ \leq \varphi_2 \leq 30^\circ$, (b) $0^\circ \leq \Phi \leq 15^\circ$, $0^\circ \leq \varphi_2 \leq 30^\circ$ (c) $40^\circ \leq \Phi \leq 50^\circ$, $0^\circ \leq \varphi_2 \leq 30^\circ$, (d) $50^\circ \leq \Phi \leq 90^\circ$, $15^\circ \leq \varphi_2 \leq 30^\circ$ (e) $50^\circ \leq \Phi \leq 90^\circ$, $0^\circ \leq \varphi_2 \leq 15^\circ$.

Additional information on micro-Raman spectroscopy

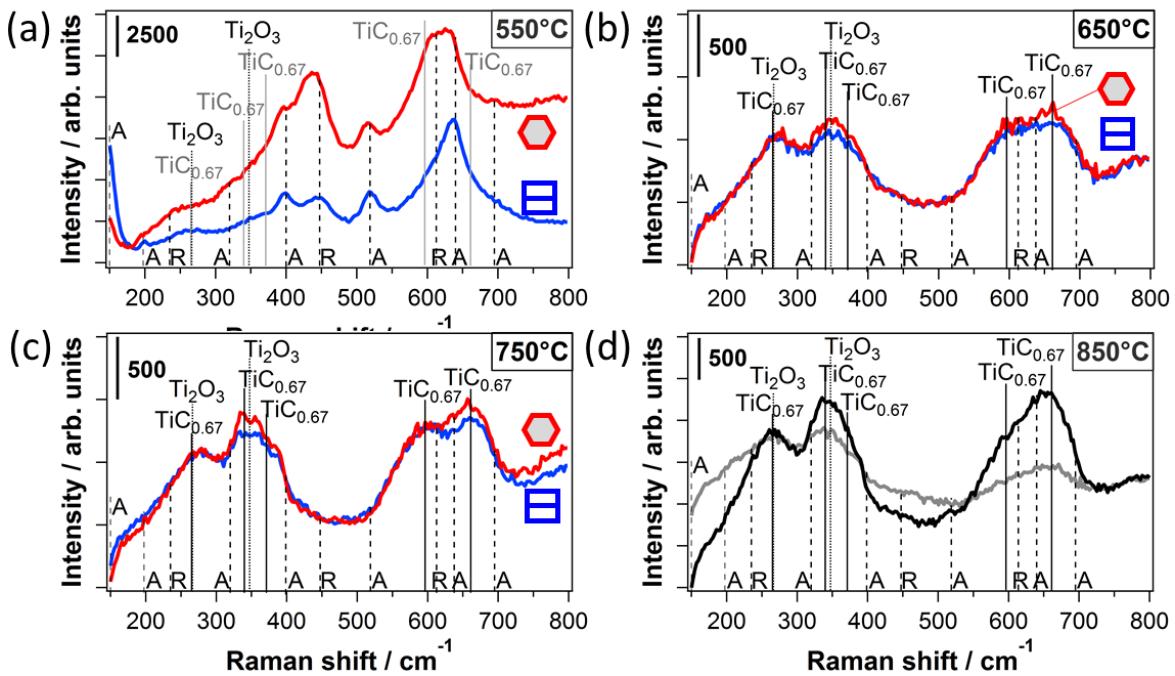


Figure S3. Micro-Raman spectra of (a) TiOC_{550} , (b) TiOC_{650} and (c) TiOC_{750} on top of $\sim\text{Ti}\{10\bar{1}0\}$ and $\sim\text{Ti}(0001)$. (d) Micro-Raman spectra of two spots on TiOC_{850} with different optical appearance. Baseline correction: constant shift to a common level.